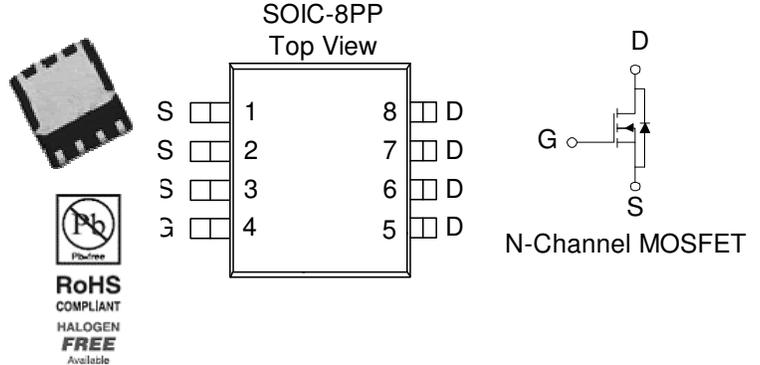


N-Channel 40-V (D-S) MOSFET

These miniature surface mount MOSFETs utilize a high cell density trench process to provide low $r_{DS(on)}$ and to ensure minimal power loss and heat dissipation. Typical applications are DC-DC converters and power management in portable and battery-powered products such as computers, printers, PCMCIA cards, cellular and cordless telephones.

- Low $r_{DS(on)}$ provides higher efficiency and extends battery life
- Low thermal impedance copper leadframe SOIC-8PP saves board space
- Fast switching speed
- High performance trench technology

PRODUCT SUMMARY		
V_{DS} (V)	$r_{DS(on)}$ m(Ω)	I_D (A)
40	9 @ $V_{GS} = 10V$	20
	12 @ $V_{GS} = 4.5V$	17



ABSOLUTE MAXIMUM RATINGS ($T_A = 25^\circ C$ UNLESS OTHERWISE NOTED)			
Parameter	Symbol	Limit	Units
Drain-Source Voltage	V_{DS}	40	V
Gate-Source Voltage	V_{GS}	± 20	
Continuous Drain Current ^a	$T_A = 25^\circ C$	± 20	A
	$T_A = 70^\circ C$	± 16	
Pulsed Drain Current ^b	I_{DM}	± 50	
Continuous Source Current (Diode Conduction) ^a	I_S	2.3	A
Power Dissipation ^a	$T_A = 25^\circ C$	5.0	W
	$T_A = 70^\circ C$	3.2	
Operating Junction and Storage Temperature Range	T_J, T_{stg}	-55 to 150	$^\circ C$

THERMAL RESISTANCE RATINGS			
Parameter	Symbol	Maximum	Units
Maximum Junction-to-Ambient ^a	$t \leq 10$ sec	25	$^\circ C/W$
	Steady State	65	$^\circ C/W$

Notes

- a. Surface Mounted on 1" x 1" FR4 Board.
- b. Pulse width limited by maximum junction temperature

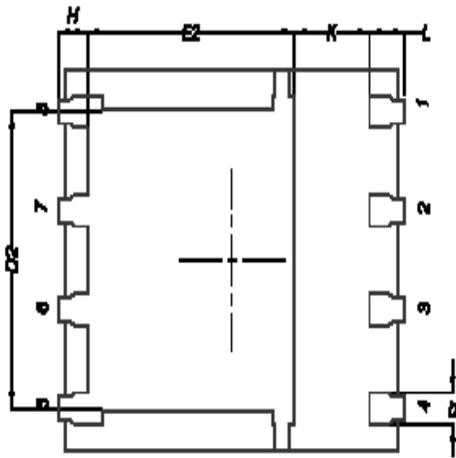
SPECIFICATIONS (T _A = 25°C UNLESS OTHERWISE NOTED)						
Parameter	Symbol	Test Conditions	Limits			Unit
			Min	Typ	Max	
Static						
Gate-Threshold Voltage	V _{GS(th)}	V _{DS} = V _{GS} , I _D = 250 uA	1		3	V
Gate-Body Leakage	I _{GSS}	V _{DS} = 0 V, V _{GS} = 20 V			±100	nA
Zero Gate Voltage Drain Current	I _{DSS}	V _{DS} = 32 V, V _{GS} = 0 V			1	uA
		V _{DS} = 32 V, V _{GS} = 0 V, T _J = 55°C			25	
On-State Drain Current ^A	I _{D(on)}	V _{DS} = 5 V, V _{GS} = 10 V	34			A
Drain-Source On-Resistance ^A	r _{DS(on)}	V _{GS} = 10 V, I _D = 7.5 A			9	mΩ
		V _{GS} = 4.5 V, I _D = 7 A			12	
Forward Transconductance ^A	g _{fs}	V _{DS} = 15 V, I _D = 7.5 A		22		S
Diode Forward Voltage	V _{SD}	I _S = 2.1 A, V _{GS} = 0 V		1.1		V
Dynamic^b						
Total Gate Charge	Q _g	V _{DS} = 15 V, V _{GS} = 4.5 V, I _D = 7.5 A		25		nC
Gate-Source Charge	Q _{gs}			5.1		
Gate-Drain Charge	Q _{gd}			12		
Input Capacitance	C _{iss}	V _{DS} = 15 V, V _{GS} = 0 V, f = 1MHz		2060		pF
Output Capacitance	C _{oss}			230		
Reverse Transfer Capacitance	C _{rss}			180		
Turn-On Delay Time	t _{d(on)}	V _{DD} = 25 V, R _L = 25 Ω, I _D = 34 A, V _{GEN} = 10 V		10		nS
Rise Time	t _r			6		
Turn-Off Delay Time	t _{d(off)}			49		
Fall-Time	t _f			18		

Notes

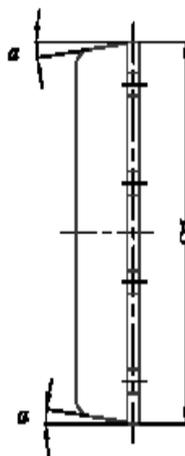
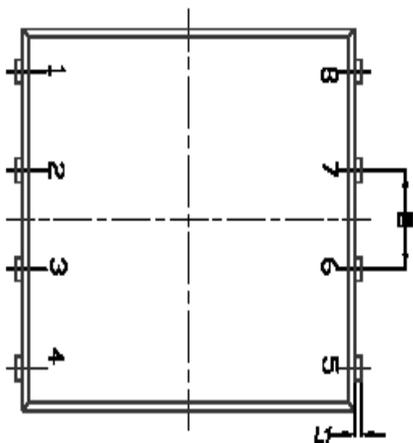
- Pulse test: PW ≤ 300us duty cycle ≤ 2%.
- Guaranteed by design, not subject to production testing.

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Package Information



BACKSIDE VIEW



DIM.	MILLIMETERS		
	MIN.	NOM.	MAX.
A	0.90	1.00	1.10
b	0.38	0.41	0.51
C	0.20	0.25	0.30
D1	4.90	4.90	5.00
D2	3.81	3.81	3.98
E	5.00	6.00	6.10
E1	5.70	6.75	5.00
E2	3.98	3.98	3.78
Ø	1.27 BSC		
H	0.41	0.51	0.51
K	1.10	-	-
L	0.51	0.51	0.71
L1	0.08	0.13	0.20
α	0°	-	12°